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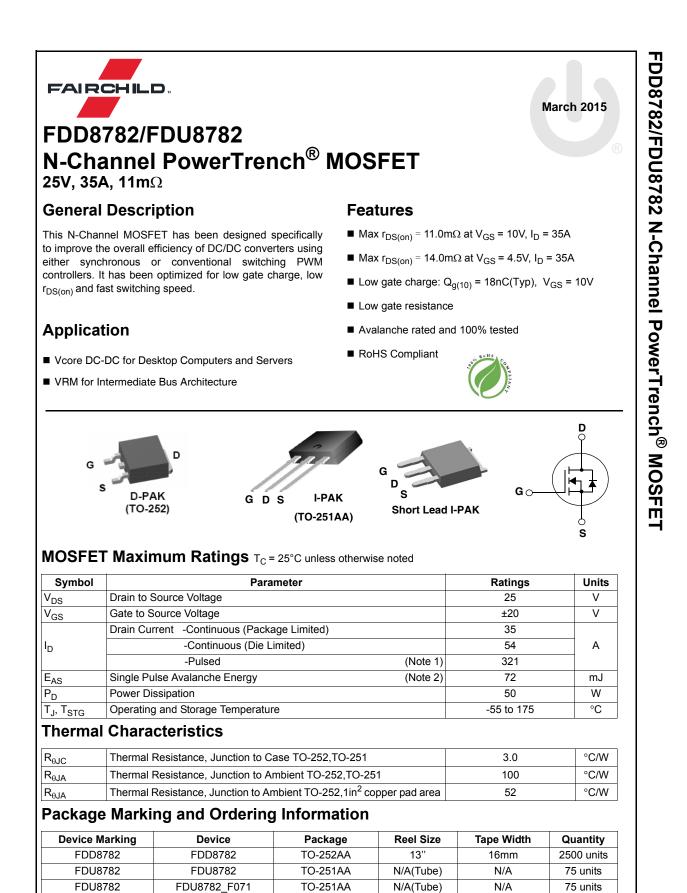


ON Semiconductor®

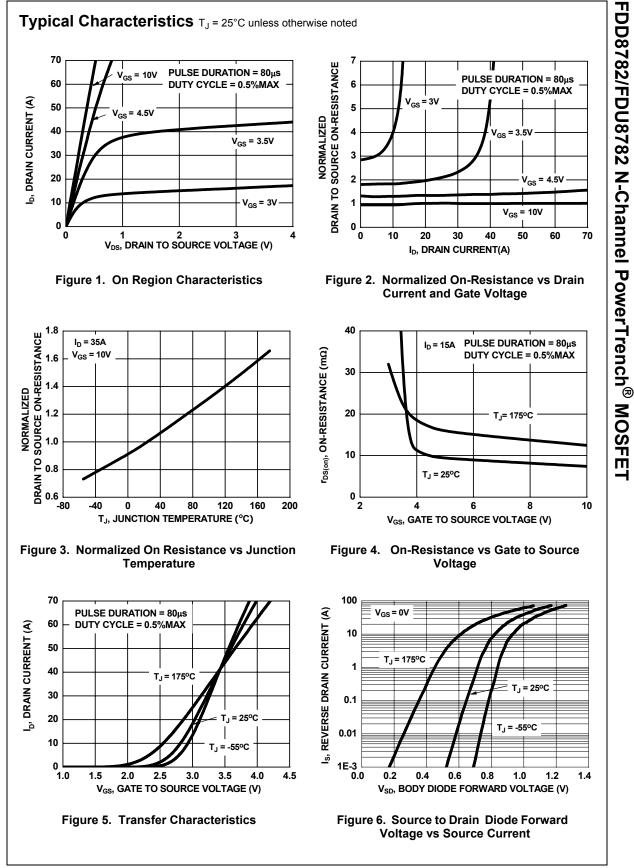
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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

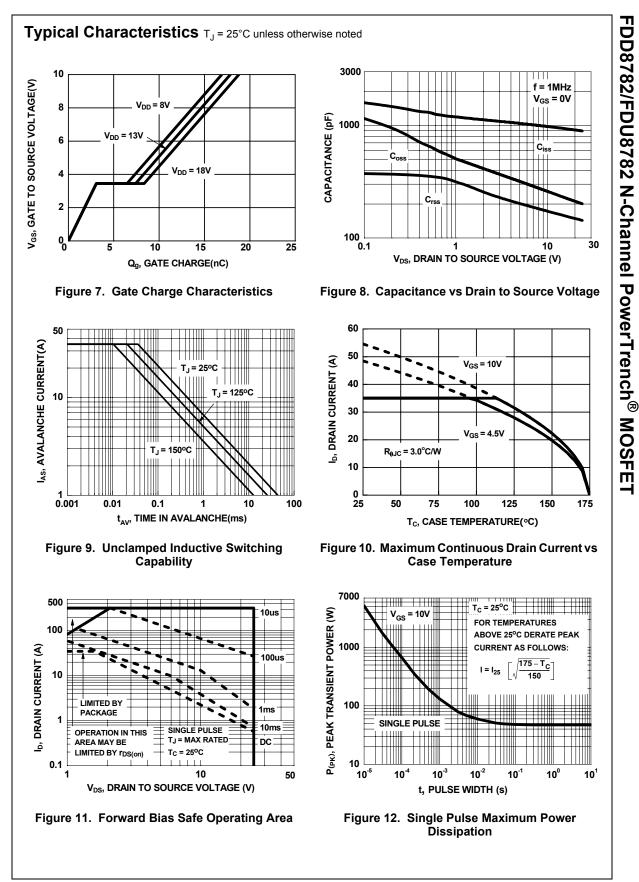
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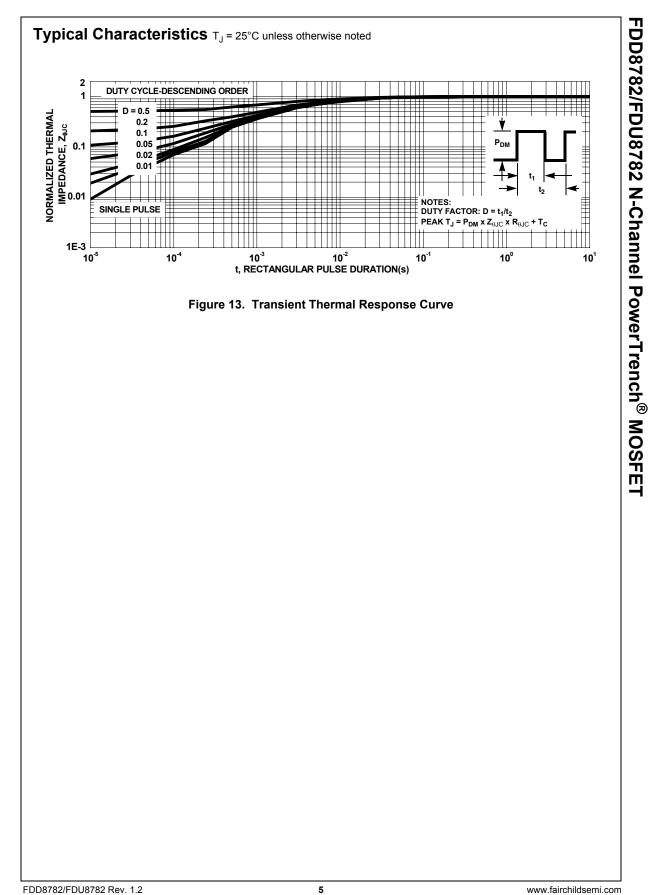
Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
Off Chara	cteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		25			V
ΔB_{VDSS}	Breakdown Voltage Temperature	$I_D = 250\mu A$, referenced to $25^{\circ}C$			14.3		mV/°C
ΔT_{J}	Coefficient				11.0		
I _{DSS}	Zero Gate Voltage Drain Current	$V_{\rm DS} = 20V,$				1	μA
	Gate to Source Leakage Current	$V_{GS} = 0V$ $V_{GS} = \pm 20V$	T _J = 150°C			250 ±100	nA
I _{GSS}	Gale to Source Leakage Current	V _{GS} - 120V				1100	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \mu A$		1.2	1.7	2.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I _D = 250μA, referenced to 25°C			-6.5		mV/°C
0	Drain to Source On Resistance	V _{GS} = 10V, I _D = 35A			8.5	11.0	- mΩ
r _{DS(on)}		V _{GS} = 4.5V, I _D = 35A			11.0	14.0	
		V _{GS} = 10V, I _D = 35A T _J = 175°C			12.1	18.0	
Dynamic	Characteristics						
C _{iss}	Input Capacitance	V _{DS} = 13V, V _{GS} = 0V, f = 1MHz			920	1220	pF
C _{oss}	Output Capacitance				230	310	pF
C _{rss}	Reverse Transfer Capacitance				160	240	pF
Rg	Gate Resistance	f = 1MHz			1.4		Ω
Switching	Characteristics						
t _{d(on)}	Turn-On Delay Time	V_{DD} = 13V, I_D = 35A V_{GS} = 10V, R_{GS} = 9 Ω			7	14	ns
t _r	Rise Time				9	18	ns
t _{d(off)}	Turn-Off Delay Time				22	36	ns
t _f	Fall Time				14	25	ns
Qg	Total Gate Charge	V_{GS} = 0V to 10V			18	25	nC
Qg	Total Gate Charge	$V_{GS} = 0V \text{ to } 10V$ $V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$ $I_a = 1.0mA$	$V_{DD} = 13V$		9.4	13	nC
Q _{gs}	Gate to Source Gate Charge			3.1		nC	
Q _{gd}	Gate to Drain "Miller"Charge	·g ·····			4.0		nC
Drain-Soເ	Irce Diode Characteristics						
V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0V, I _S = 35A			0.96	1.25	V
		$V_{GS} = 0V, I_{S} = 1$			0.86	1.2	V
t _{rr}	Reverse Recovery Time	I _F = 35A, di/dt = 100A/μs			25	38	ns
Q _{rr}	Reverse Recovery Charge	I _F = 35A, di/dt = 100A/μs			17	26	nC



FDD8782/FDU8782 Rev. 1.2



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